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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/674,396	10/01/2003	Hiroshi Tanabe	Q77312	4416
7590 08/24/2005 SUGHRUE, MION, ZINN, MACPEAK & SEAS 2100 Pennsylvania Avenue, N.W. Washington, DC 20037-3202			EXAMINER	
			MOORE, KARLA A	
			ART UNIT	PAPER NUMBER
			1763	

DATE MAILED: 08/24/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)			
	10/674,396	TANABE ET AL.			
Office Action Summary	Examiner	Art Unit			
	Karla Moore	1763			
The MAILING DATE of this communication appeariod for Reply	ppears on the cover sheet with the c	correspondence address			
A SHORTENED STATUTORY PERIOD FOR REP THE MAILING DATE OF THIS COMMUNICATION  - Extensions of time may be available under the provisions of 37 CFR 1 after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a re - If NO period for reply is specified above, the maximum statutory perio  - Failure to reply within the set or extended period for reply will, by statu.  Any reply received by the Office later than three months after the mail earned patent term adjustment. See 37 CFR 1.704(b).		nely filed s will be considered timely. the mailing date of this communication. D (35 U.S.C. § 133).			
Status					
1) Responsive to communication(s) filed on 09	June 2005.				
<u> </u>					
3) Since this application is in condition for allow					
	closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.				
Disposition of Claims					
4)  Claim(s) <u>1-6</u> is/are pending in the application 4a) Of the above claim(s) is/are withdr 5)  Claim(s) is/are allowed.  6)  Claim(s) <u>1-6</u> is/are rejected.  7)  Claim(s) is/are objected to.  8)  Claim(s) are subject to restriction and/	awn from consideration.				
Application Papers					
9) The specification is objected to by the Examination The drawing(s) filed on <u>01 October 2003</u> is/ar Applicant may not request that any objection to the Replacement drawing sheet(s) including the corresponding to	re: a)⊠ accepted or b)⊡ objected education of the drawing(s) be held in abeyance. See	e 37 CFR 1.85(a).			
11)☐ The oath or declaration is objected to by the E		• •			
Priority under 35 U.S.C. § 119					
a) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of:  1. Certified copies of the priority documer 2. Certified copies of the priority documer 3. Copies of the certified copies of the priority documer application from the International Bureat * See the attached detailed Office action for a list	nts have been received.  Ints have been received in Application on the documents have been received au (PCT Rule 17.2(a)).	on No. <u>08/886,331</u> . ed in this National Stage			
Attachment(s)	<u></u>				
1) ☑ Notice of References Cited (PTO-892) 2) ☑ Notice of Draftsperson's Patent Drawing Review (PTO-948)	4) 🔲 Interview Summary Paper No(s)/Mail Da				
3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08 Paper No(s)/Mail Date		atent Application (PTO-152)			

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#### **DETAILED ACTION**

## Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 2. Claims 1 and 6 are rejected under 35 U.S.C. 102(e) as being anticipated by U.S. Patent No. 5,861,337 to Zhang et al. (1)
- 3. Zhang et al. (1) disclose a semiconductor manufacturing apparatus as claimed in Figure 3 and comprising: a chamber capable of silicon formation (13), a chamber capable of insulating thin film formation (15), a chamber capable of laser irradiation (16), a chamber capable of hydrogen annealing (14) and transportation means (17 and 18) for transporting a substrate (19) having planar dimensions of a substrate width by a substrate length, wherein each of said chambers and said transportation means are constituted such that said substrate on which a semiconductor device is formed can be transported among said chambers without exposure of said substrate to the air; and wherein said laser irradiation chamber includes an irradiation system (26, outside chamber) and a vacuum chamber (inside 16) for accommodating the substrate, wherein the vacuum chamber has planar dimensions of a chamber length and a chamber width wherein at least one of the chamber length and chamber width is less than twice a respective length or width of the substrate (see Figure 3). The vacuum chamber has a window (27).
- 4. With respect to claim 6, which is drawn solely to a processing step of a processing method, the courts have ruled a claim containing a "recitation with respect to the manner in which a claimed apparatus is intended to be employed does not differentiate the claimed apparatus from a prior art apparatus" if the prior art apparatus teaches all the structural limitations of the claim. Ex parte Masham, 2 USPQ2d 1647 (Bd. Pat. App. & Inter. 1987). The courts have further ruled that expressions relating the apparatus to

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contents thereof during an intended operation are of no significance in determining patentability of the apparatus claim. Ex parte Thibault, 164 USPQ 666, 667 (Bd. App. 1969). In the instant case, the prior art teaches each of the structural limitations, but teaches a method using different contents/processing material.

### Claim Rejections - 35 USC § 103

- 4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 5. This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).
- 6. Claims 2-3 are rejected under 35 U.S.C. 103(a) as being unpatentable over Zhang et al. (1) as applied to claims 1 and 6 in view of U.S. Patent No. 4,529,617 to Chenevas-Paule et al.
- 7. Zhang et al. (1) disclose a semiconductor manufacturing apparatus substantially as claimed and as described above.
- 8. However, Zhang et al. (1) fail to teach the substrate held in a stationary position during laser irradiation in said laser irradiation chamber, wherein the irradiation system includes a laser and an optical system for shaping the laser beam, wherein a part of said optical system is movably disposed within said vacuum chamber such that said laser beam can be irradiated onto substantially the entire planar area of said substrate.

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9. Chenevas-Paule et al. teach that any of a substrate, radiation source/laser or deflection mirrors/ an optical system positioned in the vacuum chamber (Figure 1, 12 and 14) can be displaced and the other two components held stationary for the purpose of carrying out a scan of part or all of a substrate surface (Figures 1 and 2; column 3, rows 23-34 and column 4 rows 11-14).

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- 10. It would have been obvious to one of ordinary skill in the art at the time the Applicant's application was made to have provided a displaceable optical system/deflection mirrors and a stationary substrate in Zhang et al. (1) in order to carry out a scan of part or all of a substrate surface as taught by Chenevas-Paule et al.
- 11. Claims 4 and 5 are rejected under 35 U.S.C. 103(a) as being unpatentable over Zhang et al. (1) as applied to claims 1 and 6 in view of U.S. Patent No. 5,424,244 to Zhang et al. (2).
- 12. Zhang et al. (1) disclose a semiconductor manufacturing apparatus substantially as claimed and as described above.
- 13. However, Zhang et al. (1) fail to disclose the specific dimensions of the window as claimed (i.e. corresponding to the area of the substrate).
- 2 Zhang et al. (2) teach a window sized to correspond to the dimensions of a substrate for the purpose of avoiding locating a movable substrate holder in the processing chamber, thus making the chamber free from the associated mechanical parts and dust (Figure 8A; column 14, rows 19-49).
- 15. It would have been obvious to one of ordinary skill in the art at the time the Applicant's invention was made to have provided a window sized to correspond to the dimensions of the substrate Zhang et al. (1) in order to avoid locating a movable substrate holder in a processing chamber, thus making the chamber free from the associated mechanical parts and dust as taught by Zhang et al. (2).

# Response to Arguments

16. Applicant's arguments filed 9 June 2005 have been fully considered but they are not persuasive. Zhang et al. discloses a chamber *capable* of hydrogen annealing. Examiner does not submit that Zhang discloses a comparable processing method as the claimed invention, and need not, as the pending

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claims are drawn to an apparatus, not a method. What Zhang et al. discloses is a chamber capable of annealing and that would also be capable of performing a hydrogen annealing process, if that were the desired/intended method to be conducted in the chamber and hydrogen was supplied as a processing material. Examiner notes that the courts have ruled that a claim containing a "recitation with respect to the manner in which a claimed apparatus is intended to be employed does not differentiate the claimed apparatus from a prior art apparatus" if the prior art apparatus teaches all the structural limitations of the claim. Ex parte Masham, 2 USPQ2d 1647 (Bd. Pat. App. & Inter. 1987). The courts have further ruled that expressions relating the apparatus to contents thereof during an intended operation are of no significance in determining patentability of the apparatus claim. Ex parte Thibault, 164 USPQ 666, 667 (Bd. App. 1969). Further, regardless of Applicant's argument addressed above, which depend on an intended use of the claimed apparatus, there is another issue. Examiner recognizes that the prior art chamber in question is taught as being useful for annealing to treat a film containing hydrogen, rather than a chamber performing a process using hydrogen as a processing gas as performed in Applicant's intended method. However, there is no rule that a chamber be referred to using the name of a processing gas to be used, rather than being referred to based on an object to be worked upon. When referring to the chamber as a "hydrogen annealing" chamber, either is a possibility.

17. With respect to Applicant's argument that Zhang fails to teach each of said processing chambers and transportation means are constituted such that said substrate on which a semiconductor device is formed can be transported among said chambers without exposure of said substrate to the air, Examiner directs Applicant's attention to column 7, rows 33-45, where this is clearly disclosed.

#### Conclusion

18. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. 4591821 teaches annealing in inert, reducing and dry oxidizing atmospheres.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Karla Moore whose telephone number is 571.272.1440. The examiner can normally be reached on Monday-Friday, 8:30am-5:30pm.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor,

Gregory Mills can be reached on 571.272.1439. The fax phone number for the organization where this

application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application

Information Retrieval (PAIR) system. Status information for published applications may be obtained from

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at 866-217-9197 (toll-free).

km

20 August 2005

Parviz Hassanzadeh

Supervisory Patent Examiner

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